



# BUK763R9-60E

N-channel TrenchMOS standard level FET

28 July 2016

Product data sheet

## 1. General description

Standard level N-channel MOSFET in a SOT404 package using TrenchMOS technology. This product has been designed and qualified to AEC Q101 standard for use in high performance automotive applications.

## 2. Features and benefits

- AEC Q101 compliant
- Repetitive avalanche rated
- Suitable for thermally demanding environments due to 175 °C rating
- True standard level gate with VGS(th) rating of greater than 1V at 175 °C

## 3. Applications

- 12 V Automotive systems
- Motors, lamps and solenoid control
- Start-Stop micro-hybrid applications
- Transmission control
- Ultra high performance power switching

## 4. Quick reference data

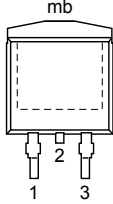
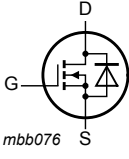
Table 1. Quick reference data

| Symbol                         | Parameter                        | Conditions   |     | Min | Typ  | Max | Unit |
|--------------------------------|----------------------------------|--|-----|-----|------|-----|------|
| V <sub>DS</sub>                | drain-source voltage             | T <sub>J</sub> ≥ 25 °C; T <sub>J</sub> ≤ 175 °C  |     | -   | -    | 60  | V    |
| I <sub>D</sub>                 | drain current                    | V <sub>GS</sub> = 10 V; T <sub>mb</sub> = 25 °C; <a href="#">Fig. 2</a>  | [1] | -   | -    | 100 | A    |
| P <sub>tot</sub>               | total power dissipation          | T <sub>mb</sub> = 25 °C; <a href="#">Fig. 1</a>  |     | -   | -    | 263 | W    |
| <b>Static characteristics</b>  |                                  |  |     |     |      |     |      |
| R <sub>DSon</sub>              | drain-source on-state resistance | V <sub>GS</sub> = 10 V; I <sub>D</sub> = 25 A; T <sub>J</sub> = 25 °C; <a href="#">Fig. 11</a>                           |     | -   | 2.94 | 3.9 | mΩ   |
| <b>Dynamic characteristics</b> |                                  |  |     |     |      |     |      |
| Q <sub>GD</sub>                | gate-drain charge                | I <sub>D</sub> = 25 A; V <sub>DS</sub> = 48 V; V <sub>GS</sub> = 10 V; <a href="#">Fig. 13</a> ; <a href="#">Fig. 14</a> |     | -   | 33   | -   | nC   |

[1] Continuous current is limited by package.

## 5. Pinning information

Table 2. Pinning information

| Pin | Symbol | Description                       | Simplified outline  | Graphic symbol  |
|-----|--------|-----------------------------------|---|---|
| 1   | G      | gate                              |  <p>D2PAK (SOT404)</p> |  |
| 2   | D      | drain                             |   |   |
| 3   | S      | source                            |   |   |
| mb  | D      | mounting base; connected to drain |   |   |

## 6. Ordering information

Table 3. Ordering information

| Type number  | Package |  |         |
|--------------|---------|--|---------|
|              | Name    | Description  | Version |
| BUK763R9-60E | D2PAK   | plastic single-ended surface-mounted package (D2PAK); 3 leads (one lead cropped) | SOT404  |

## 7. Marking

Table 4. Marking codes

| Type number  | Marking code |
|--------------|--------------|
| BUK763R9-60E | BUK763R9-60E |

## 8. Limiting values

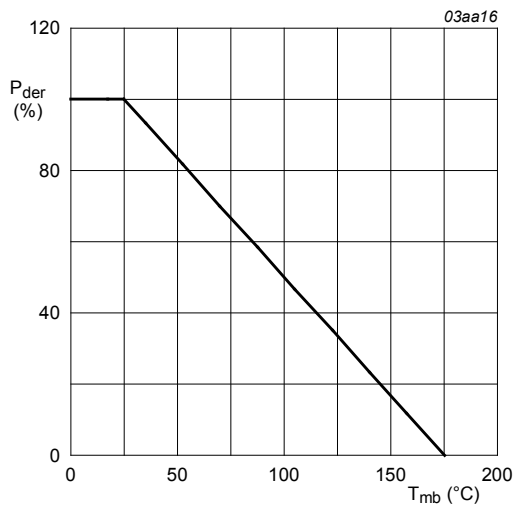
Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol    | Parameter               | Conditions  |     | Min | Max | Unit |
|-----------|-------------------------|---|-----|-----|-----|------|
| $V_{DS}$  | drain-source voltage    | $T_j \geq 25\text{ °C}$ ; $T_j \leq 175\text{ °C}$  |     | -   | 60  | V    |
| $V_{DGR}$ | drain-gate voltage      | $R_{GS} = 20\text{ k}\Omega$  |     | -   | 60  | V    |
| $V_{GS}$  | gate-source voltage     | $T_j \leq 175\text{ °C}$ ; DC   |     | -20 | 20  | V    |
| $P_{tot}$ | total power dissipation | $T_{mb} = 25\text{ °C}$ ; <a href="#">Fig. 1</a>  |     | -   | 263 | W    |
| $I_D$     | drain current           | $T_{mb} = 25\text{ °C}$ ; $V_{GS} = 10\text{ V}$ ; <a href="#">Fig. 2</a>                   | [1] | -   | 100 | A    |
|           |                         | $T_{mb} = 100\text{ °C}$ ; $V_{GS} = 10\text{ V}$ ; <a href="#">Fig. 2</a>                  | [1] | -   | 100 | A    |
| $I_{DM}$  | peak drain current      | $T_{mb} = 25\text{ °C}$ ; pulsed; $t_p \leq 10\text{ }\mu\text{s}$ ; <a href="#">Fig. 3</a> |     | -   | 706 | A    |
| $T_{stg}$ | storage temperature     |   |     | -55 | 175 | °C   |
| $T_j$     | junction temperature    |   |     | -55 | 175 | °C   |

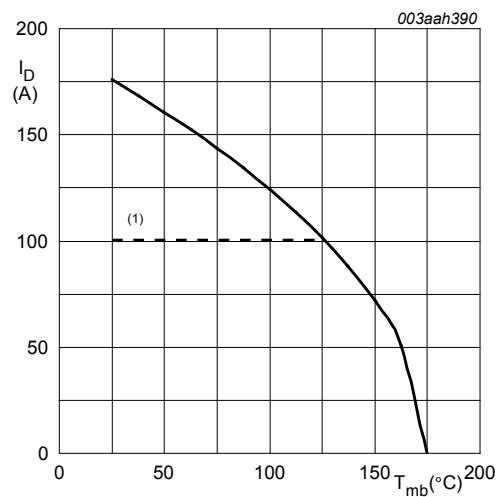
| Symbol                      | Parameter                                    | Conditions   |        | Min | Max | Unit |
|-----------------------------|--|--|--------|-----|-----|------|
| <b>Source-drain diode</b>   |  |  |        |     |     |      |
| $I_S$                       | source current                               | $T_{mb} = 25\text{ °C}$  | [1]    | -   | 100 | A    |
| $I_{SM}$                    | peak source current                          | pulsed; $t_p \leq 10\ \mu\text{s}$ ; $T_{mb} = 25\text{ °C}$   |        | -   | 706 | A    |
| <b>Avalanche ruggedness</b> |  |  |        |     |     |      |
| $E_{DS(AL)S}$               | non-repetitive drain-source avalanche energy | $I_D = 100\text{ A}$ ; $V_{sup} \leq 60\text{ V}$ ; $R_{GS} = 50\ \Omega$ ;<br>$V_{GS} = 60\text{ V}$ ; $T_{j(\text{init})} = 25\text{ °C}$ ; unclamped;<br><a href="#">Fig. 4</a> | [2][3] | -   | 372 | mJ   |

- [1] Continuous current is limited by package.
- [2] Single-pulse avalanche rating limited by maximum junction temperature of 175 °C.
- [3] Refer to application note AN10273 for further information.



**Fig. 1. Normalized total power dissipation as a function of mounting base temperature**

$$P_{der} = \frac{P_{tot}}{P_{tot(25^\circ\text{C})}} \times 100\%$$



(1) Capped at 100A due to package

**Fig. 2. Continuous drain current as a function of mounting base temperature**

$$V_{GS} \geq 10\text{V}$$

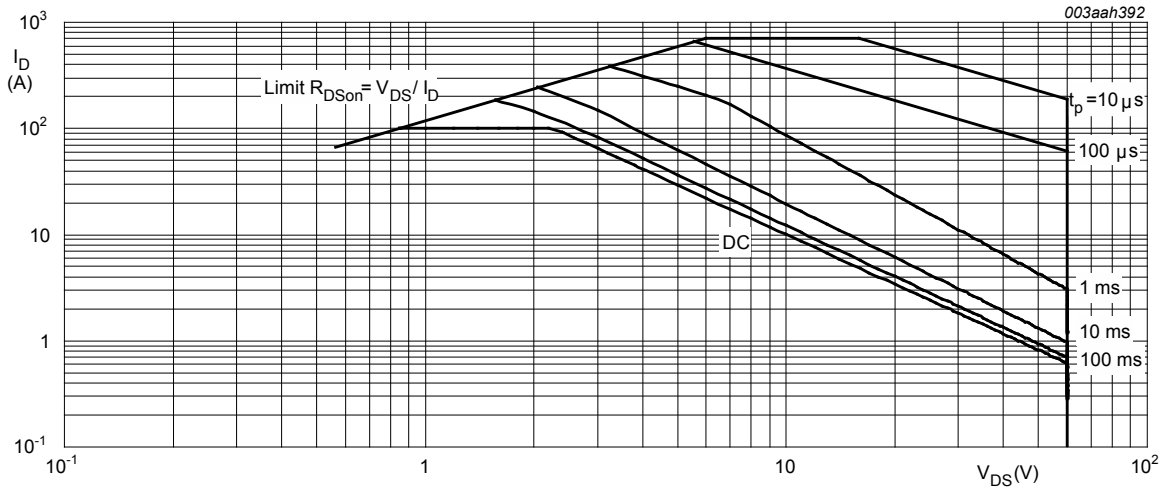


Fig. 3. Safe operating area; continuous and peak drain currents as a function of drain-source voltage

$T_{mb} = 25^\circ C$ ;  $I_{DM}$  is a single pulse

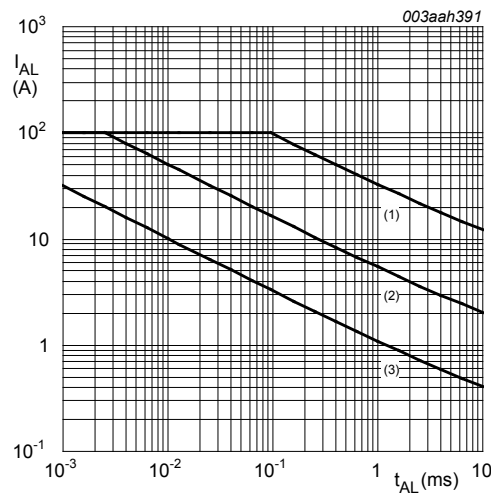


Fig. 4. Single pulse avalanche rating; avalanche current as a function of avalanche time

(1)  $T_{j(init)} = 25^\circ C$ ; (2)  $T_{j(init)} = 150^\circ C$ ; (3) Repetitive Avalanche

## 9. Thermal characteristics

Table 6. Thermal characteristics

| Symbol         | Parameter   | Conditions   | Min | Typ | Max  | Unit |
|----------------|---|--|-----|-----|------|------|
| $R_{th(j-mb)}$ | thermal resistance from junction to mounting base | <a href="#">Fig. 5</a>                                 | -   | -   | 0.57 | K/W  |
| $R_{th(j-a)}$  | thermal resistance from junction to ambient       | minimum footprint ; mounted on a printed-circuit board | -   | 50  | -    | K/W  |

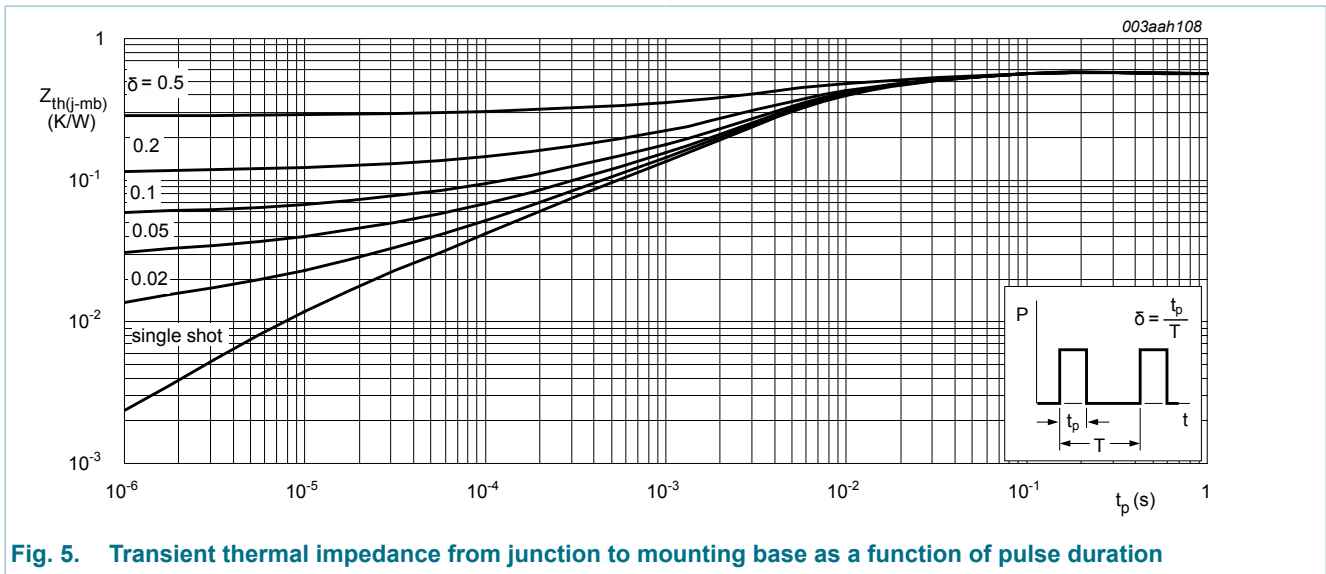


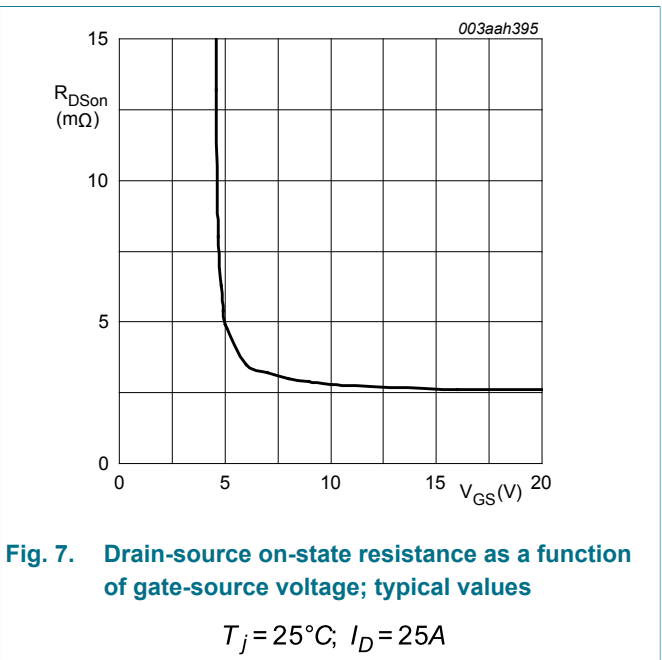
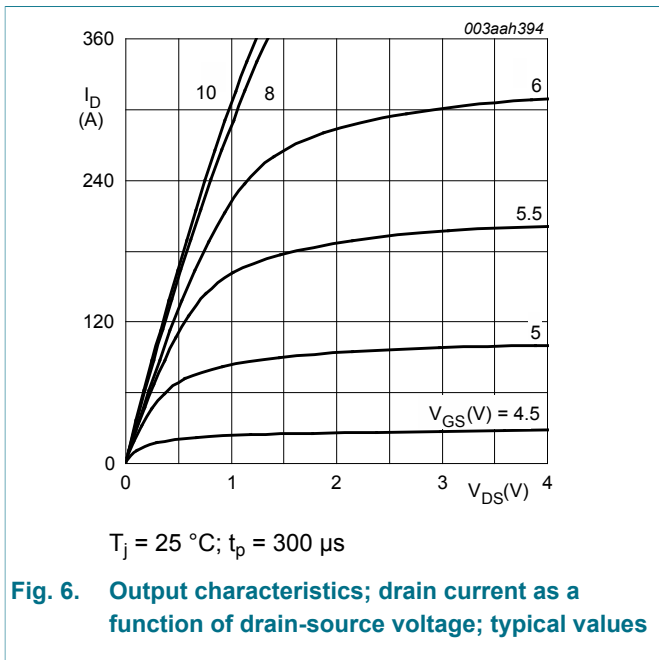
Fig. 5. Transient thermal impedance from junction to mounting base as a function of pulse duration

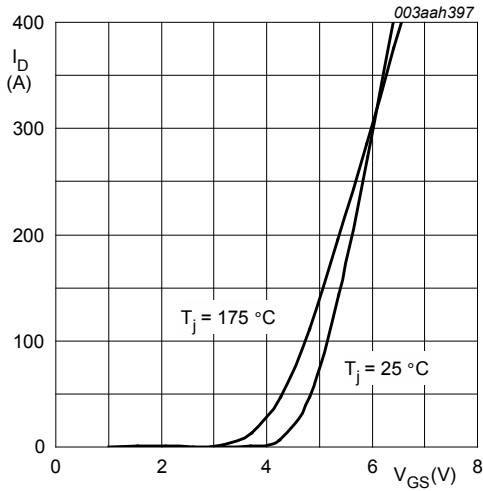
## 10. Characteristics

Table 7. Characteristics

| Symbol                         | Parameter                        | Conditions   | Min | Typ  | Max | Unit       |
|--------------------------------|----------------------------------|--|-----|------|-----|------------|
| <b>Static characteristics</b>  |                                  |  |     |      |     |            |
| $V_{(BR)DSS}$                  | drain-source breakdown voltage   | $I_D = 250 \mu A; V_{GS} = 0 V; T_J = 25 \text{ }^\circ C$   | 60  | -    | -   | V          |
|                                |                                  | $I_D = 250 \mu A; V_{GS} = 0 V; T_J = -55 \text{ }^\circ C$  | 54  | -    | -   | V          |
| $V_{GS(th)}$                   | gate-source threshold voltage    | $I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_J = 25 \text{ }^\circ C;$<br><a href="#">Fig. 9; Fig. 10</a> | 2.4 | 3    | 4   | V          |
|                                |                                  | $I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_J = 175 \text{ }^\circ C;$<br><a href="#">Fig. 9</a>         | 1   | -    | -   | V          |
|                                |                                  | $I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_J = -55 \text{ }^\circ C;$<br><a href="#">Fig. 9</a>         | -   | -    | 4.5 | V          |
| $I_{DSS}$                      | drain leakage current            | $V_{DS} = 60 V; V_{GS} = 0 V; T_J = 25 \text{ }^\circ C$   | -   | 0.07 | 1   | $\mu A$    |
|                                |                                  | $V_{DS} = 60 V; V_{GS} = 0 V; T_J = 175 \text{ }^\circ C$  | -   | -    | 500 | $\mu A$    |
| $I_{GSS}$                      | gate leakage current             | $V_{GS} = 20 V; V_{DS} = 0 V; T_J = 25 \text{ }^\circ C$   | -   | 2    | 100 | nA         |
|                                |                                  | $V_{GS} = -20 V; V_{DS} = 0 V; T_J = 25 \text{ }^\circ C$  | -   | 2    | 100 | nA         |
| $R_{DS(on)}$                   | drain-source on-state resistance | $V_{GS} = 10 V; I_D = 25 \text{ A}; T_J = 25 \text{ }^\circ C;$<br><a href="#">Fig. 11</a>           | -   | 2.94 | 3.9 | m $\Omega$ |
|                                |                                  | $V_{GS} = 10 V; I_D = 25 \text{ A}; T_J = 175 \text{ }^\circ C;$<br><a href="#">Fig. 11; Fig. 12</a> | -   | -    | 8.5 | m $\Omega$ |
| <b>Dynamic characteristics</b> |                                  |  |     |      |     |            |
| $Q_{G(tot)}$                   | total gate charge                | $I_D = 25 \text{ A}; V_{DS} = 48 V; V_{GS} = 10 V;$<br><a href="#">Fig. 13; Fig. 14</a>              | -   | 103  | -   | nC         |
| $Q_{GS}$                       | gate-source charge               |  | -   | 25.1 | -   | nC         |
| $Q_{GD}$                       | gate-drain charge                |  | -   | 33   | -   | nC         |

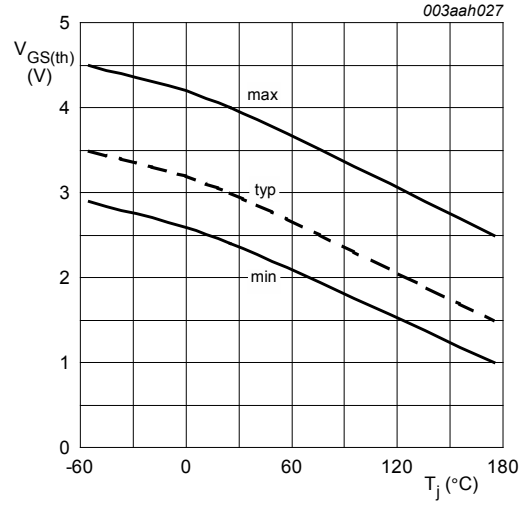
| Symbol                    | Parameter                    | Conditions  | Min | Typ  | Max  | Unit |
|---------------------------|------------------------------|---|-----|------|------|------|
| $C_{iss}$                 | input capacitance            | $V_{GS} = 0\text{ V}; V_{DS} = 25\text{ V}; f = 1\text{ MHz};$                                    | -   | 5609 | 7480 | pF   |
| $C_{oss}$                 | output capacitance           | $T_j = 25\text{ }^\circ\text{C};$ <a href="#">Fig. 15</a>   | -   | 737  | 884  | pF   |
| $C_{rss}$                 | reverse transfer capacitance |   | -   | 455  | 624  | pF   |
| $t_{d(on)}$               | turn-on delay time           | $V_{DS} = 45\text{ V}; R_L = 1.8\text{ }\Omega; V_{GS} = 10\text{ V};$                            | -   | 25.3 | -    | ns   |
| $t_r$                     | rise time                    | $R_{G(ext)} = 5\text{ }\Omega$  | -   | 41.4 | -    | ns   |
| $t_{d(off)}$              | turn-off delay time          |   | -   | 62.7 | -    | ns   |
| $t_f$                     | fall time                    |   | -   | 45   | -    | ns   |
| $L_D$                     | internal drain inductance    | from upper edge of mounting base to centre of die   | -   | 2.5  | -    | nH   |
| $L_S$                     | internal source inductance   | measured from source lead to source bond pad  | -   | 7.5  | -    | nH   |
| <b>Source-drain diode</b> |                              |   |     |      |      |      |
| $V_{SD}$                  | source-drain voltage         | $I_S = 25\text{ A}; V_{GS} = 0\text{ V}; T_j = 25\text{ }^\circ\text{C};$ <a href="#">Fig. 16</a> | -   | 0.8  | 1.2  | V    |
| $t_{rr}$                  | reverse recovery time        | $I_S = 20\text{ A}; di_S/dt = -100\text{ A}/\mu\text{s}; V_{GS} = 0\text{ V};$                    | -   | 39   | -    | ns   |
| $Q_r$                     | recovered charge             | $V_{DS} = 25\text{ V}$  | -   | 51   | -    | nC   |





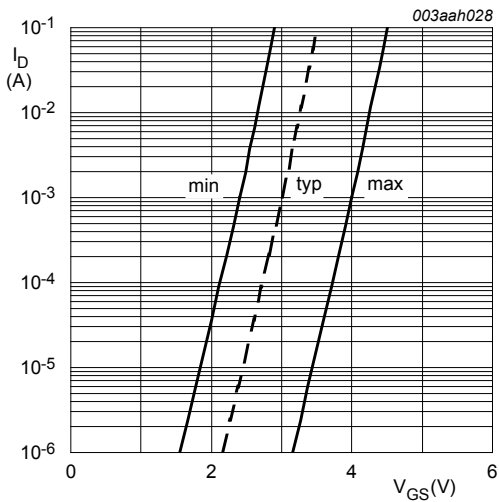
**Fig. 8. Transfer characteristics; drain current as a function of gate-source voltage; typical values**

$V_{DS} = 10V$



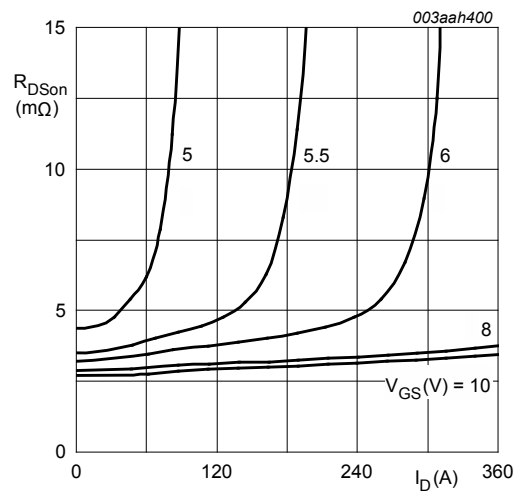
**Fig. 9. Gate-source threshold voltage as a function of junction temperature**

$I_D = 1 \text{ mA}; V_{DS} = V_{GS}$



**Fig. 10. Sub-threshold drain current as a function of gate-source voltage**

$T_j = 25^\circ\text{C}; V_{DS} = 5V$



**Fig. 11. Drain-source on-state resistance as a function of drain current; typical values**

$T_j = 25^\circ\text{C}; t_p = 300 \mu\text{s}$

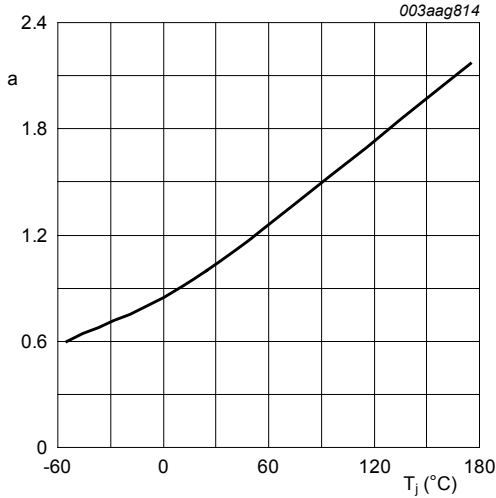


Fig. 12. Normalized drain-source on-state resistance factor as a function of junction temperature

$$a = \frac{R_{DSon}}{R_{DSon}(25^\circ\text{C})}$$



Fig. 13. Gate charge waveform definitions

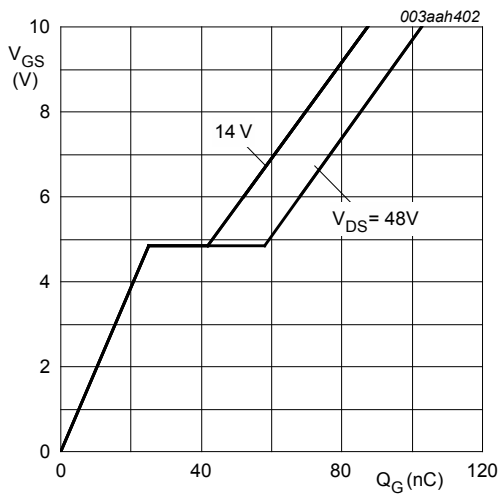


Fig. 14. Gate-source voltage as a function of gate charge; typical values

$$T_j = 25^\circ\text{C}; I_D = 25\text{A}$$

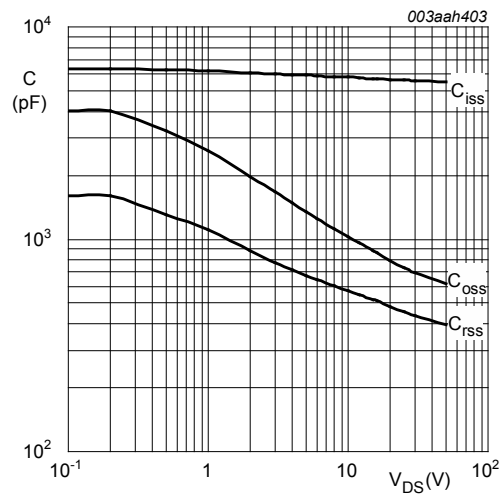
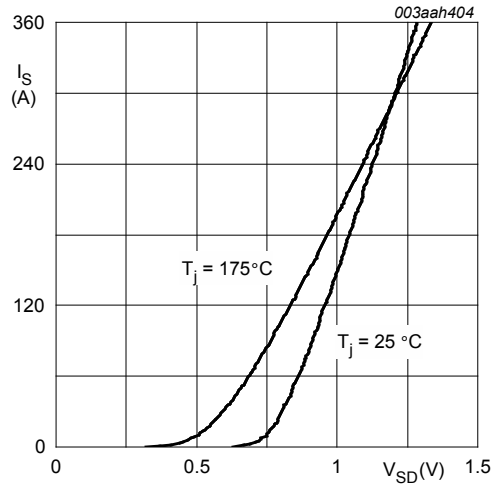


Fig. 15. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

$$V_{GS} = 0\text{V}; f = 1\text{MHz}$$





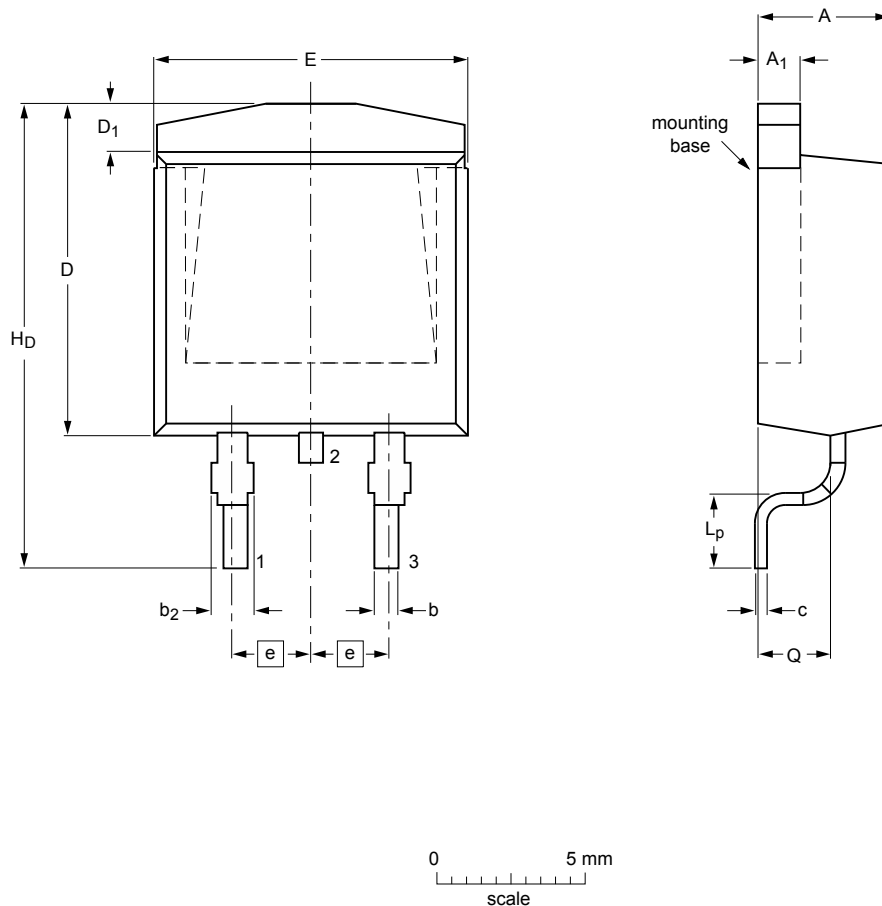
**Fig. 16. Source (diode forward) current as a function of source-drain (diode forward) voltage; typical values**

$$V_{GS} = 0V$$

### 11. Package outline

Plastic single-ended surface-mounted package (D2PAK); 3 leads (one lead cropped)

SOT404



Dimensions (mm are the original dimensions)

| Unit | A   | A <sub>1</sub> | b    | b <sub>2</sub> | c    | D  | D <sub>1</sub> | E    | e    | H <sub>D</sub> | L <sub>p</sub> | Q   |
|------|-----|----------------|------|----------------|------|----|----------------|------|------|----------------|----------------|-----|
| max  | 4.5 | 1.40           | 0.85 | 1.45           | 0.64 | 11 | 1.6            | 10.3 |      | 15.8           | 2.9            | 2.6 |
| nom  |     |                |      |                |      |    |                |      | 2.54 |                |                |     |
| min  | 4.1 | 1.27           | 0.60 | 1.05           | 0.46 |    | 1.2            | 9.7  |      | 14.8           | 2.1            | 2.2 |

sot404\_po

| Outline version | References |       |       | European projection | Issue date             |
|-----------------|------------|-------|-------|---------------------|------------------------|
|                 | IEC        | JEDEC | JEITA |                     |                        |
| SOT404          |            |       |       |                     | -06-03-16-<br>13-02-25 |

Fig. 17. Package outline D2PAK (SOT404)

## 12. Legal information

### 12.1 Data sheet status

| Document status [1][2]         | Product status [3] | Definition  |
|--------------------------------|--------------------|---|
| Objective [short] data sheet   | Development        | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification      | This document contains data from the preliminary specification.                       |
| Product [short] data sheet     | Production         | This document contains the product specification.                                     |

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nexperia.com>.

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